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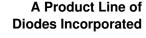
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

















#### **60V NPN MEDIUM POWER TRANSISTOR** PowerDI<sup>®</sup>5

#### **Features**

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- $V_{CEO} = 60V$
- $I_C = 6A$ ;  $I_{CM} = 20A$
- Low Saturation voltage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

### **Applications**

- Motor driver
- Regulator circuit

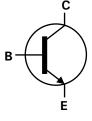
#### **Mechanical Data**

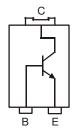
- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.093 grams (approximate)





**Bottom View** 





**Device Schematic** 

Pin-out diagram

#### Ordering Information (Note 3)

Part Number	Case	Packaging
DXT2010P5-13	PowerDI <sup>®</sup> 5	5000/Tape & Reel

Notes:

1. No purposefully added lead. Halogen and Antimony Free.

Top View

- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

### **Marking Information**



DXT2010 = Product Type Marking Code Oll = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)





# Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	6	Α
Peak Pulse Current	I <sub>CM</sub>	20	А

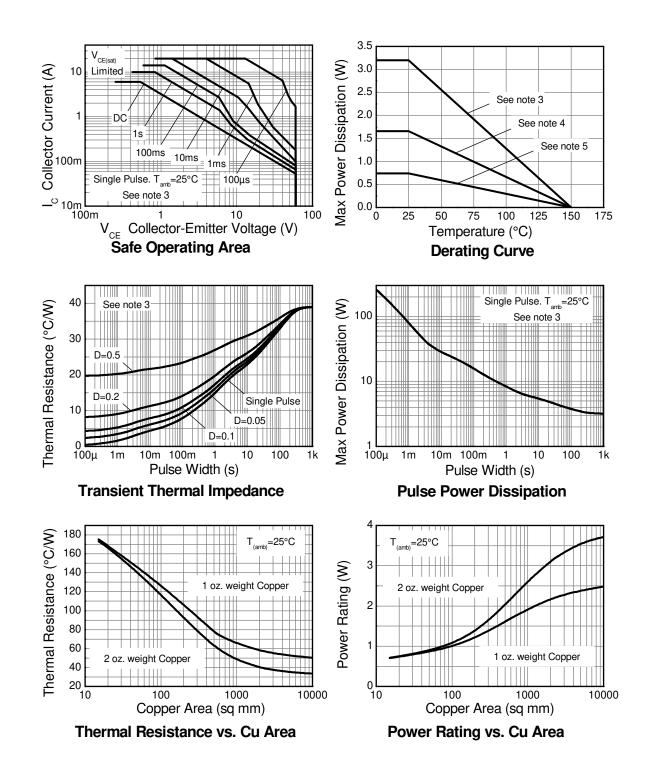
# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation @ T <sub>A</sub> = 25°C (Note 4)	$P_D$	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T <sub>A</sub> = 25°C	$R_{ heta JA}$	39	°C/W
Power Dissipation @ T <sub>A</sub> = 25°C (Note 5)	$P_D$	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T <sub>A</sub> = 25°C	$R_{ heta JA}$	75	°C/W
Power Dissipation @ T <sub>A</sub> = 25°C (Note 6)	$P_D$	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) @T <sub>A</sub> = 25°C	$R_{ heta JA}$	169	°C/W
Thermal Resistance, Junction to Collector Terminal	$R_{ hetaJT}$	5.6	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 25mm x 25mm.
  Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 50mm x 50mm.
  Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.









# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

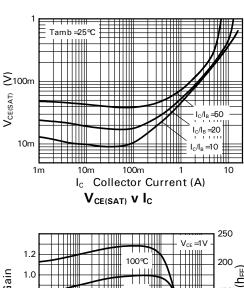
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	150	190	_	V	$I_C = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	V <sub>(BR)CEO</sub>	60	80	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	7.0	8.1	_	V	$I_E = 100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_		20 0.5	nA μA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>amb</sub> = 100 °C
Collector Cutoff Current	I <sub>CER</sub> R≤1kΩ	_	_	20 0.5	nA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>amb</sub> = 100 °C
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	10	nA	V <sub>EB</sub> = 6V
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	_	20 45 50 100 210	30 60 70 135 260	mV	$I_C = 100$ mA, $I_B = 5$ mA $I_C = 1$ A, $I_B = 100$ mA $I_C = 1$ A, $I_B = 50$ mA $I_C = 2$ A, $I_B = 50$ mA $I_C = 6$ A, $I_B = 300$ mA
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	_	1000	1100	mV	I <sub>C</sub> = 6A, I <sub>B</sub> = 300mA
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	_	940	1050	mV	$V_{CE} = 1V, I_{C} = 6A$
DC Current Gain (Note 6)	h <sub>FE</sub>	100 100 55 20	200 200 105 40	300 — —	_	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 1V I <sub>C</sub> = 2A, V <sub>CE</sub> = 1V I <sub>C</sub> = 5A, V <sub>CE</sub> = 1V I <sub>C</sub> = 10A, V <sub>CE</sub> = 1V
Transition Frequency	f <sub>T</sub>	_	130	_	MHz	$I_C = 100 \text{mA}, \ V_{CE} = 10 \text{V}$ f = 50MHz
Output Capacitance (Note 7)	$C_{obo}$	_	31	_	pF	V <sub>CB</sub> = -10A, f = 1MHz
Switching Times	t <sub>on</sub> t <sub>off</sub>	_	42 760	_	ns ns	$I_C = 1A$ , $V_{CC} = 10V$ , $I_{B1} = I_{B2} = 100mA$

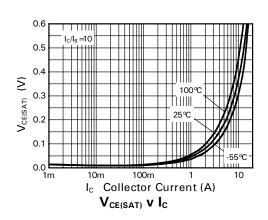
Notes: 7. Pulse Test: Pulse width  $\leq$ 300 $\mu$ s. Duty cycle  $\leq$ 2.0%.

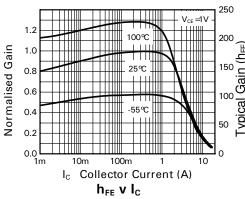


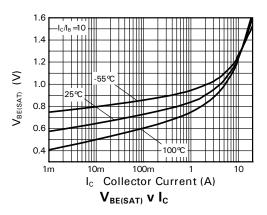


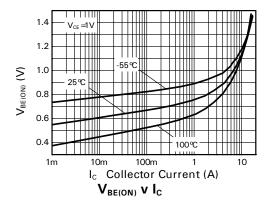
# **Typical Characteristic**





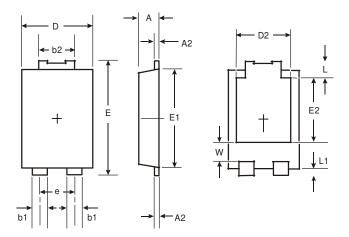






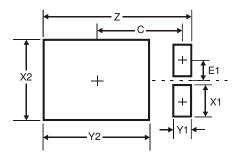


# **Package Outline Dimensions**



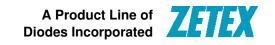
PowerDI <sup>®</sup> 5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	3.90	4.05		
D2	3.054 Typ			
Е	6.40	6.60		
е	1.84 Typ			
E1	5.30	5.45		
E2	3.549 Typ			
L	0.75	0.95		
L1	0.50	0.65		
W	1.10	1.41		
All Dimensions in mm				

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
F1	0.9





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